

Lower output capacitance (C type) and on resistance (R type). ($C \times R10$) High speed switching. (C type: Turn on time: 0.03ms, Turn off time: 0.03ms).

FEATURES

1. Two option package available. R type offers greatly reduced onresistance.

C type offers lower output capacitance.

	AQY221R2S (R type)	AQY221N2S (C type)
Output capacitance: C	13pF	1pF
On resistance: R	0.8Ω	9.5Ω

2. High speed switching

Turn on time: 30µs (AQY221N2S) Turn off time: 30µs (AQY221N2S)

3. Super miniature design SOP 4-pin type.

4. Low-level off state leakage current of 10pA

The SSR has an off state leakage current of several milliamperes, where as this PhotoMOS relay has typ. 10pA (typical) even with the rated load voltage (AQY221N2S)

RF PhotoMOS (AQY221O2S)

TYPICAL APPLICATIONS

Measuring and testing equipment 1. Testing equipment for semiconductor performance

IC tester, Liquid crystal driver tester, semiconductor performance tester

2. Board tester

Bare board tester, In-circuit tester, function tester

3. Medical equipment

Ultrasonic wave diagnostic machine 4. Multi-point recorder Warping, thermo couple

TYPES

Circuit arrangement Type		Output	rating*	Tape and reel	Pooking quantity	
		Load voltage	Load current	Picked from the 1/2-pin side	Picked from the 3/4-pin side	Packing quantity
1 Form A	R type	40 V	250 mA	AQY221R2SX	AQY221R2SZ	Tana and real 1 000 per
	C type	40 V	120 mA	AQY221N2SX	AQY221N2SZ	Tape and reel: 1,000 pcs.

* Indicate the peak AC and DC values.

Notes:

(1) Tape package is the standard packing style. Also available in tube.

(Part No. suffix "X" or "Z" is not needed when ordering; Tube: 100 pcs.; Case: 2,000 pcs.)

(2) For space reasons, the initial letters of the product number "AQY and S", the package type indicator "X" and "Z" are omitted from the seal.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

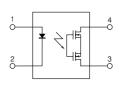
	Item	Symbol	AQY221R2S (R type)	AQY221N2S (C type)	Remarks
Input	LED forward current	IF	50mA		
	LED reverse voltage	VR	5V		
	Peak forward current	IFP	1A		f=100 Hz, Duty factor=0.1%
	Power dissipation	Pin	75mW		
Output	Load voltage (peak AC)	VL	40V		
	Continuous load current	١L	0.25A 0.12A		Peak AC,DC
	Peak load current	Ipeak	0.75A 0.30A		100 ms (1 shot), VL= DC
	Power dissipation	Pout	300mW		
Total power dissipation		Р⊤	350mW		
I/O isolation voltage		Viso	500V AC	1,500V AC	
Temperature limits	Operating	Topr	-40°C to +85°C -40°F to +185°F		Non-condensing at low temperatures
	Storage	Tstg	-40°C to +100°C -40°F to +212°F		



<R type>



mm inch

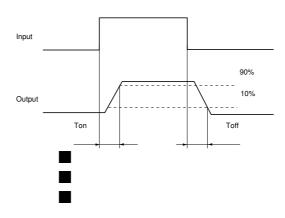


RF PhotoMOS (AQY221O2S)

	aracteristic	s (Ambient temp	erature: 25		AQY221R2S	AQY221N2S	O a se altilizar
Item				Symbol	(R type)	(C type)	Condition
			Typical		0.5 mA	0.9 mA	I∟ = 250 mA (R type)
	LED operate current		Maximum	Fon	3.0	0 mA	I∟ = 80 mA (C type)
					0.1 mA	0.2 mA	I∟ = 250 mA (R type)
Input	LED turn off current		Typical	Foff	0.4 mA	0.85 mA	I∟ = 80 mA (C type)
					1.25 V (1.14 V at I⊧ = 5 mA)		
	LED dropout voltage		Typical Maximum	VF	1.5 V		l⊧ = 50 mA
					0.8Ω	9.5Ω	l⊧ = 5 mA
	On resistar	On resistance		Ron			I∟ = 250 mA (R type),
	On resistance		Maximum		1.25Ω	12.5Ω	I∟ = 80 mA (C type) Within 1 s on time
Output			Typical		13 pF	1.0 pF	I⊧ = 0 mA
Output	Output capacitance		Maximum	Cout	18 pF	1.5 pF	$V_B = 0 V$ f = 1 MHz
		Off state leakage current			0.03 nA	0.01 nA	$I_F = 0 \text{ mA}$
	Off state lea			Leak	10 nA		$V_{L} = Max.$
			Typical		0.1 ms	0.03 ms	I⊧ = 5 mA
	Switching speed	Turn on time*		Ton			VL = 10V
			Maximum		0.5ms		R∟ = 40Ω (R type), 125Ω (C type)
			Typical		0.06 ms	0.03 ms	l⊧ = 5 mA
Transfer		Turn off time*		Toff			V _L = 10V
characteristics			Maximum	1011	0.:	2 ms	R _L = 40Ω (R type), 125Ω (C type)
	I/O capacitance Initial I/O isolation resistance		Typical		0.	8 pF	f = 1 MHz
			Maximum	Ciso	1.5 pF		V _B = 0 V
			Minimum	Riso	1,000ΜΩ		500 V DC

Note: Recommendable LED forward current $I_F = 5$ mA.

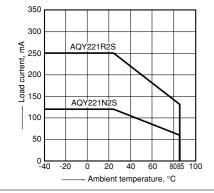




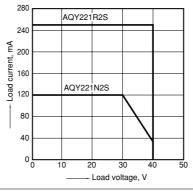
REFERENCE DATA

1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F

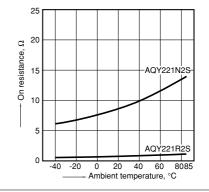


2. Load current vs. Load voltage characteristics Ambient temperature: 25°C $77^\circ {\sf F}$



3. On resistance vs. ambient temperature characteristics

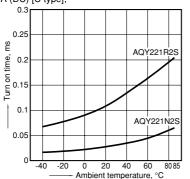
Measured portion: between terminals 3 and 4 LED current: 5 mA; Load voltage: Max. (DC); Load current: 250mA (DC) [R type], 80mA (DC) [C type];



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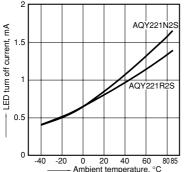
4. Turn on time vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4 LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 250mA (DC) [R type], 80mA (DC) [C type];



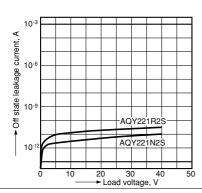
7. LED turn off current vs. ambient temperature characteristics

Load voltage: Max. (DC); Continuous load current: 250mA (DC) [R type], 80mA (DC) [C type];



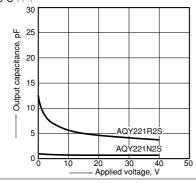
10. Off state leakage current vs. load voltage characteristics

Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



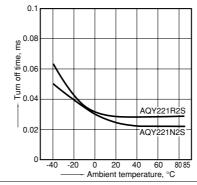
13. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4 Frequency: 1 MHz, 30m Vrms; Ambient temperature: 25°Ċ 77

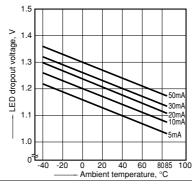


5. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10V (DC); Continuous load current: 250mA (DC) [R type], 80mA (DC) [C type];



8. LED dropout voltage vs. ambient temperature characteristics LED current: 5 to 50 mA



11. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4 Load voltage: 10V (DC);

Continuous load current: 250mA (DC) [R type], 80mA (DC) [C type]; Ambient temperature: 25°C 77°F

0.3 0.25 ms time, 0.2 AQY221R2S 5 0.15 Turn 0.1 QY221N2 0.0 0 L 0

14. Isolation vs. frequency characteristics $(50\Omega \text{ impedance})$

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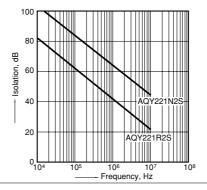
50

60

30

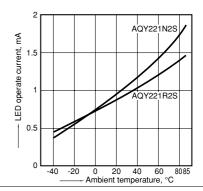
LED forward current, mA

Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



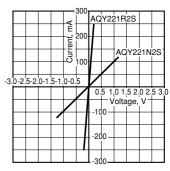
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6. LED operate current vs. ambient temperature characteristics Load voltage: Max. (DC); Continuous load current: 250mA (DC) [R type], 80mA (DC) [C type];



9. Current vs. voltage characteristics of output at MOS portion Measured portion: between terminals 3 and 4

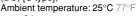
Ambient temperature: 25°C 77°F

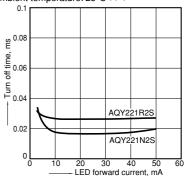


12. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4 Load voltage: 10V (DC);

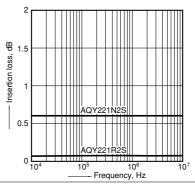
Continuous load current: 250mA (DC) [R type], 80mA (DC) [C type];





15. Insertion loss vs. frequency characteristics $(50\Omega \text{ impedance})$

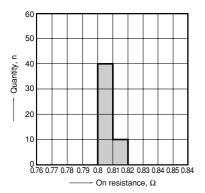
Measured portion: between terminals 3 and 4 Ambient temperature: 25°C 77°F



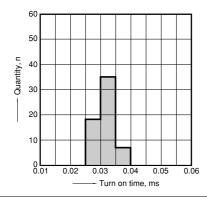
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16-(1). On resistance distribution (R type) Measured portion: between terminals 3 and 4 Continuous load current: 250mA (DC) Ambient temperature: 25°C 77°F

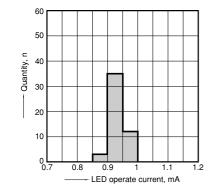


17-(2). Turn on time distribution (C type) Load voltage: 10V (DC) Continuous load current: 80mA (DC) Ambient temperature: 25°C 77°F

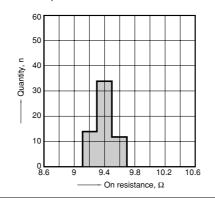


19-(1). LED operate current distribution (R type) Load voltage: 10V (DC)

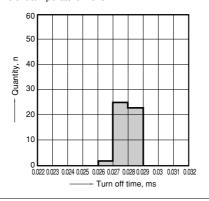
Continuous load current: 250mA (DC) Ambient temperature: 25°C 77°F



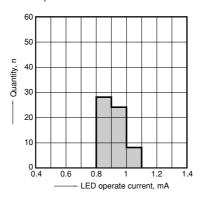
16-(2). On resistance distribution (C type) Measured portion: between terminals 3 and 4 Continuous load current: 80mA (DC) Ambient temperature: 25°C 77°F



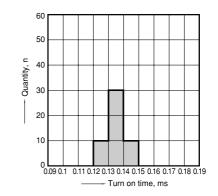
18-(1). Turn off time distribution (R type) Load voltage: 10V (DC) Continuous load current: 250mA (DC) Ambient temperature: 25°C 77°F



19-(2). LED operate current distribution (C type) Load voltage: 10V (DC) Continuous load current: 80mA (DC) Ambient temperature: 25°C 77°F



17-(1). Turn on time distribution (R type) Load voltage: 10V (DC) Continuous load current: 250mA (DC) Ambient temperature: 25°C 77°F



18-(2). Turn off time distribution (C type) Load voltage: 10V (DC) Continuous load current: 80mA (DC) Ambient temperature: 25°C 77°F

